

SI-8511NVS

Surface-Mount, Synchronous Rectifier Step-down Switching Mode Control ICs

Features

- Surface-mount package (TSSOP24)
- High efficiency due to synchronous rectification: 92% (at VIN = 5V, IO = 1A, VO = 2.5V)
- Capable of downsize a choke-coil due to IC's high switching frequency (400kHz typ, On Time Control). (Compared with conventional Sanken devices)
- Low reference voltage (Vref) of 1.1V. The output voltage is variable from 1.1V to 6V.
- High-speed response to a load
- Compatible with low ESR capacitors
- Soft start and output ON/OFF available
- Built-in overcurrent and output-overvoltage protection circuits
- PWRGD function to indicate the output voltage status
- High precision reference voltage: 1.1V ± 1.2%

Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	Ratings	Unit
Control-System DC Input Voltage	Vcc	7	V
DC Input Voltage	VIN	25	V
Boost Block Input Voltage	VH	30	V
EN Terminal Input Voltage	VEN	Vcc	V
PWRGD Terminal Applied Voltage	VPWRGD	7	V
Junction Temperature	Tj	+150	°C
Storage Temperature	Tstg	−40 to +150	°C

Applications

- Power supplies for notebook PCs and mobile devices
- Onboard local power supplies
- OA equipment
- For stabilization of the secondary-side output voltage of switching power supplies

Recommended Operating Conditions

Parameter	Symbol	Ratings	Unit
Control System Input Voltage Range	Vcc	4.5 to 5.5	V
Input Voltage Range	VIN	3 to 18	V
Output Voltage Range	VO	1.1 to 6	V
Operating Temperature Range	Top	−20 to +85	°C

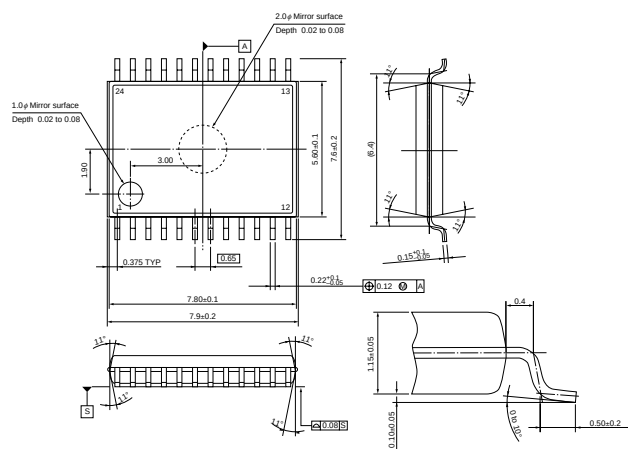
Electrical Characteristics

(Ta=25°C unless otherwise specified)

Parameter		Symbol	Ratings			Unit	Conditions
			min.	typ.	max.		
Dynamic Characteristics	Output Voltage	VO	−1.2%	1.1	+1.2%	V	VIN=5V, Vcc=5V, VSNS connected to VO, IO=0A
	Temperature Coefficient of Output Voltage	ΔVO/ΔT		±0.03		mV/°C	VIN=5V, Vcc=5V, VSNS connected to VO, IO=0A, Ta=0 to 85°C
Circuit Current	Circuit Current (Vcc Terminal)	Iop			6	mA	Vcc=5V, EN=H, FADJ:open
	Circuit Current (VIN Terminal)	Iop			1	mA	VIN=5V, EN=H
	Standby Current 1 (Vcc Terminal)	Istd1			100	μA	Vcc=5V, EN=L
	Standby Current 2 (VIN Terminal)	Istd2			50	μA	VIN=5V, EN=L
Undervoltage Lockout	UVLO Operating Voltage 1 (Vcc Terminal)	Vuvlo1	3.7		4.45	V	VIN=5V
	UVLO Operating Voltage 2 (VIN Terminal)	Vuvlo2	2.5		2.9	V	Vcc=5V
On Time Control	On Time	Ton		1.27		μS	Vcc=5V, VIN=5V, VO=2.5V
	Minimum Off Time	Toff		0.7		μS	Vcc=5V
	REF Terminal Voltage	Vref	1.1	1.2	1.3	V	Vcc=5V
	REF Terminal Source Current	Iref			100	μA	Vcc=5V
High Side Drive	On Resistance (high side)	RonHH		5.5		Ω	VH-VLIN=5V
	On Resistance (low side)	RonHL		5.5		Ω	VH-VLIN=5V
Low Side Drive	On Resistance (high side)	RonLH		5.5		Ω	Vcc=5V
	On Resistance (low side)	RonLL		5.5		Ω	Vcc=5V
Bootstrap	Bootstrap Voltage	VH-VLIN	4.5	5	5.5	V	
Protection System	Current for Current Limit Detection	Ilim	90	100	110	μA	Vcc=5V, VIN=5V
	Soft Start Terminal Current	Iss		±20		μA	Vcc=5V
	EN Low Level Voltage	Vcelo	0		0.8	V	Vcc=5V
	EN High Level Voltage	Vcehi	2.4		Vcc	V	Vcc=5V
	EN Bias Level Current	ICE			5	μA	Vcc=5V, EN=5V
	PWRGD Good Voltage (high side)	Vsens		1.32		V	Vcc=5V
	PWRGD Good Voltage (low side)	Vsens		0.88		V	Vcc=5V
	PWRGD Low Output Voltage	Vpwrgd			0.4	V	Vcc=5V, Ipwrgd=120μA
	PWRGD Terminal Current	Ipwrgd			120	μA	Vcc=5V, Vpwrgd=0.4V
	PWRGD Leakage Current	Ipwrgd			5	μA	Vpwrgd=5V

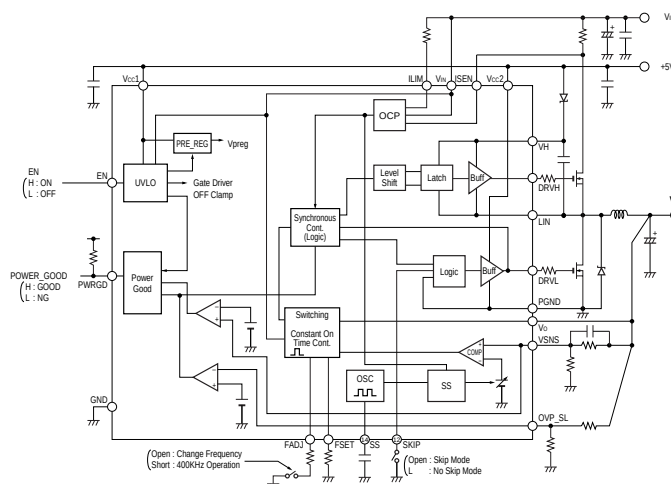
■ External Dimensions (TSSOP24)

(Unit : mm)

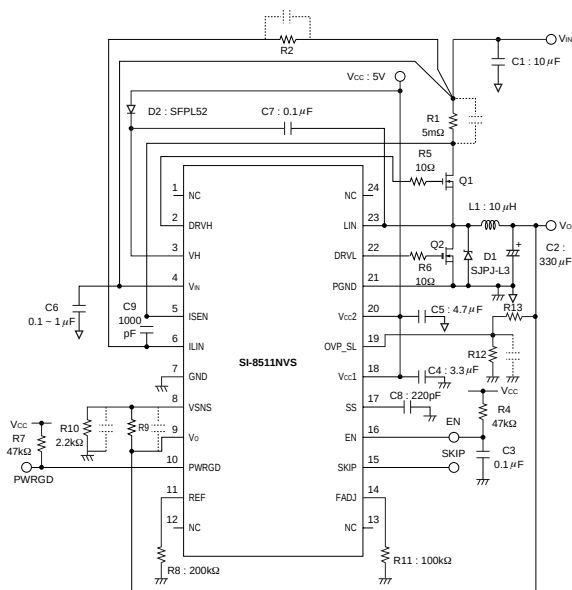


Plastic Mold Package Type
Flammability: UL94V-0
Product Mass: Approx. 1.36g

■Block Diagram (Pin Assignment)



■ Typical Connection Diagram



MOS FET Q_1, Q_2

- Be sure to use logic type MOS FET as Q₁ and Q₂.
If you use a normal power MOS FET type, the ON resistance may not drop to a satisfactory level due to a shortage of V_{GS}. This may deteriorate the efficiency and cause overheating.

Diode D_1

- Be sure to use a Schottky-barrier diode for D1.
If other diodes like fast recovery diodes are used, IC may be destroyed because of the reverse voltage generated by the recovery voltage or ON voltage.

Choke coil L_1

- If the winding resistance of the choke coil is too high, the efficiency may drop below the rated value.
- Take care concerning heat radiation from the choke coil caused by magnetic saturation due to overload or short-circuit load.

Capacitor C_1, C_2

- As large ripple currents flow through C₁ and C₂, use high-frequency and low-impedance capacitors suitable for switching mode power supplies. Especially when the impedance of C₂ is high, the switching waveform may become abnormal at low temperatures. For C₂, do not use a capacitor with an extremely low equivalent series resistance (ESR) such as a ceramic capacitor, which may cause an abnormal oscillation.

* To create the optimum operating conditions, place the components as close as possible to each other.